



Engineering

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				Course S	peci	ification	S					
Program (s) on which this course is				Electronics & Electrical Communications Engineering								
given:												
Major or Minor element of programs:				Major Electronics & Electrical Communication Engineering								
Department offering the program:												
Department offering the course:				Electronics &	Ele	ctrical Con	imunica	tion Eng	ineering			
Academic year / Level:				First year								
Date of original/modified specification				2003/								
approval: Semester of course offering:			Spring 2011									
A- Basic Infor	0											
1.a. Title:	a. Title: Electronics (1)			1.b. Code: ELC 101 B								
2. Units/Credit	2.a. Lect		2	2.b. Tutori	<u>_1</u>	2	2.c. Pra	ation1		2 d Total	4	
hours per week:	2.a. Lect	ures	Ζ	2.0. Tutori	al	2	2.C. Pra	actical		2.d. Total	4	
1. Overall Aims of the Course:This course introduces bipolar junction transistors and MOSFETS. Operating analysis and small signal models are introduced and applied to simple of Optoelectronic devices (photoconductor – photovoltaic detectors – solar cells – L and semiconductor laser and fiberoptics.a) Knowledge and Understanding								rcuits.				
2. Intended Learning Outcomes of Course (ILOs):		 Describe the device properties of BJT, MOSFETS (1.2) Distinguish large signal and small signal models (1.7) Identify major single stage amplifier circuits. (1.7) Describe properties of optoelectronic devices and applications. (1.2) b) Intellectual Skills Analyze the performance of single stage electronic circuits (3.1) Compare BJT and MOSFET circuits and different amplifier topologies. (3.4) c) Professional and Practical Skills Produce operating point, DC and transient simulations of electronic circuits on a circuit simulator using BJT and MOSFETS in some electronic applications (2.1, 2.6) d) General and Transferable Skills Demonstrate efficient IT capabilities (4.2) Illustrate ability to use multiple references and sources (4.6) 										
3. Contents			Tat	alhauna	L				Tutorial	/ Ducation		
1			al hours	Lectures			Tutorial/ Practical					
BJT biasing 6				2				4				
BJT small signal model6BJT amplifiers6			6		2 2			4 4				
1 · · · · · · · · · · · · · · · · · · ·												
<u>e</u>								2	4			
<u> </u>												
1				4 4								
8			8		4 4							
Optoelectronic detectors 6												
LEDS - Laser 2			2		2 0							

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Solar energy converter

	Lectures (Y) Class Activity (Y)		Practical Training/ Laboratory (N)	Seminar/Workshop (N) Projects (Y)				
4. Teaching and Learning Methods			Case Study (N)					
	E-learning	g (N)	Assignments /Homework (Y)	Other:				
5. Student Assessment Methods								
5.a. Method		To assess (with reference to the ILOs)						
-Class test		a1, b1						
-Mid-term exam		a1, a2, a3, a4, b1, b2						
-Project		c1, c2, d1						
-Quizes and homeworks		a1, a2, a3, a4, b1, b2, c1						
5.b. Assessment Schedule		Week						
-Assessment 1; Class test		4						
-Assessment 2; Mid-term exam		8						
-Project		12						
-Final-term Examination		15						
5.c. Weighting of Assessments								
-Mid-Term Examination			15 %					
-Project		10%						
-Final-term Examination		70 %						
-Semester Work		5%						
-Total		100 %						
6. List of References								
6.a. Course Notes								
6.b. Essential Books (Text Books)								
 Microelectronic circuits (Sed Semiconductor Devices (M. Semiconductor Devices) 		·						
6.c.Recommended Books								
Microelectronic circuit designSolid state electronic Devices)					
6.d. Periodicals, Web Sites, etc: N	/A							
7. Facilities Required for Teaching	and Learn	ing						
Course Coordinator: Prof. Dr. Sameh Said								
Head of Department: Prof. Dr. M	Prof. Dr. Mahmoud El-Hadidi							
ate: 2010 - 2011								